NSN 5961-00-311-3004

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-311-3004 **Inclosure Material:** Glass and metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.187 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 6.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 binding post Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0